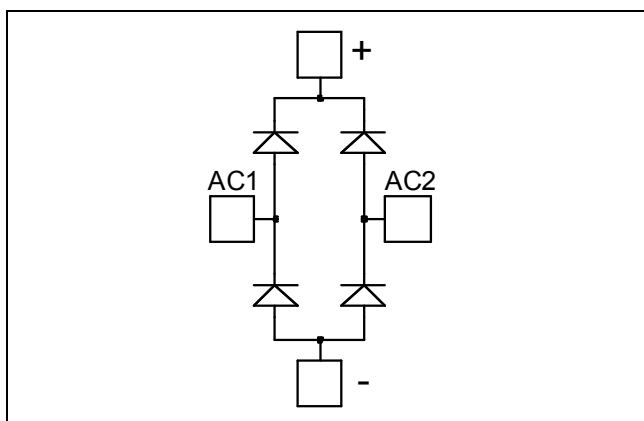


Diode Full Bridge Power Module

$$V_{RRM} = 200V$$

$$I_C = 100A @ T_c = 80^{\circ}C$$



Application

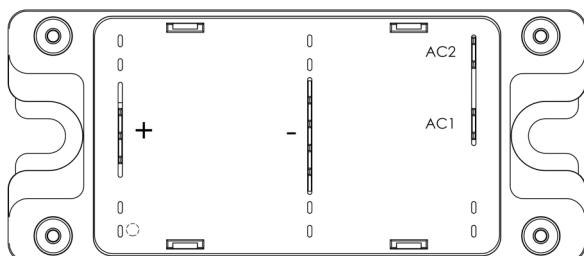
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant



Absolute maximum ratings

<i>Symbol</i>	<i>Parameter</i>				<i>Max ratings</i>	<i>Unit</i>
V _R	Maximum DC reverse Voltage				200	V
V _{RRM}	Maximum Peak Repetitive Reverse Voltage					
I _{F(AV)}	Maximum Average Forward Current	Duty cycle = 50%	T _C = 25°C	145	A	
			T _C = 80°C	100		
I _{F(RMS)}	RMS Forward Current	Duty cycle = 50%	T _C = 45°C	145		
I _{FSM}	Non-Repetitive Forward Surge Current		8.3ms	T _C = 45°C	500	



CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_F	Diode Forward Voltage	$I_F = 100\text{A}$			1.0	1.1	V
		$I_F = 200\text{A}$			1.4		
		$I_F = 100\text{A}$	$T_j = 125^\circ\text{C}$		0.9		
I_{RM}	Maximum Reverse Leakage Current	$V_R = 200\text{V}$	$T_j = 25^\circ\text{C}$			250	μA
			$T_j = 125^\circ\text{C}$			500	
C_T	Junction Capacitance	$V_R = 200\text{V}$			400		pF

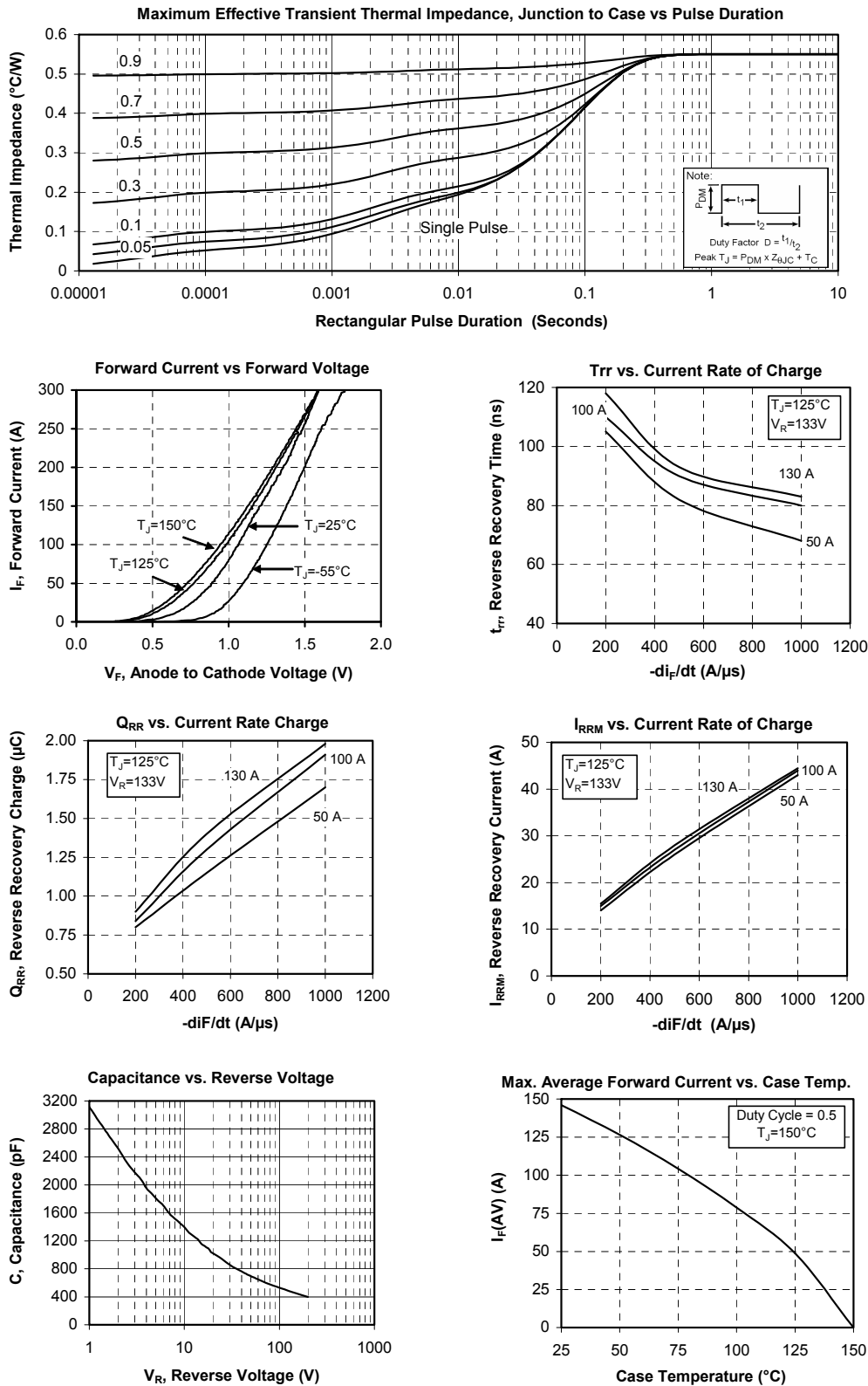
Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
t _{rr}	Reverse Recovery Time	I _F =1A,V _R =30V di/dt = 100A/μs	T _j = 25°C		39		ns	
t _{rr}	Reverse Recovery Time	I _F = 100A V _R = 133V di/dt = 200A/μs	T _j = 25°C		60		ns	
			T _j = 125°C		110			
Q _{rr}	Reverse Recovery Charge		T _j = 25°C		200		nC	
			T _j = 125°C		840			
I _{RRM}	Reverse Recovery Current		T _j = 25°C		6		A	
			T _j = 125°C		15			
t _{rr}	Reverse Recovery Time	I _F = 100A V _R = 133V di/dt=1000A/μs	T _j = 125°C		80		ns	
Q _{rr}	Reverse Recovery Charge				1.91		μC	
I _{RRM}	Reverse Recovery Current				44		A	

Thermal and package characteristics

Symbol	Characteristic	Min		Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance				0.55	$^\circ\text{C}/\text{W}$
V_{ISOL}	RMS Isolation Voltage, any terminal to case $t = 1\text{ min}, 50/60\text{Hz}$	4000				V
T_j	Operating junction temperature range	-40			150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-40			125	
T_C	Operating Case Temperature	-40			100	
Torque	Mounting torque	To Heatsink	M5	2.5	4.7	N.m
Wt	Package Weight				160	g

Typical Performance Curve





Technical drawing of a mechanical part, showing three views: top, front, and side. The drawing includes dimensions and tolerances for various features.

Top View Dimensions:

- Overall width: 93 ± 0.50
- Overall height: 80 ± 0.20
- Distance between mounting holes: 11.6^* , 30.50^* , 26.40^*
- Mounting hole diameter: $\phi 6.1 \pm 0.2$
- Internal features: 3.81^* , 5.72^* , 1.91^* , 15.24^* , 11.43^* , 3.81^*

Front View Dimensions:

- Overall width: 78.50 ± 0.25
- Overall height: 17.20 ± 0.30
- Distance between mounting holes: 0.50 ± 0.05
- Mounting hole diameter: $\phi 2.50 \pm 0.10$, $\phi 2 \pm 0.10$
- Internal features: 1 ± 0.10 , 7 ± 0.20

Side View Dimensions:

- Overall width: 21.2 ± 1
- Overall height: 40.40 ± 0.50
- Internal features: $5.50 - 0.05$, 11 ± 0.5 , 3 ± 0.20 , 5 ± 0.50 , 1.20 ± 0.05

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